

NCP3337

Ultra High Accuracy, Low Iq, 500 mA with Power Good Low Dropout Regulator

The NCP3337 is a high performance, low dropout regulator. With accuracy of $\pm 0.9\%$ over line and load and ultra-low quiescent current and noise it encompasses all of the necessary features required by today's consumer electronics. This unique device is guaranteed to be stable without a minimum load current requirement and stable with any type of capacitor as small as 1.0 μF . The NCP3337 also comes equipped with sense and noise reduction pins to increase the overall utility of the device. The NCP3337 offers reverse bias protection.

Features

- High Accuracy Over Line and Load ($\pm 0.9\%$ at 25°C)
- Ultra-Low Dropout Voltage at Full Load (260 mV typ)
- No Minimum Output Current Required for Stability
- Low Noise (33 μVrms w/10 nF C_{nr} and 52 μVrms w/out C_{nr})
- Low Shutdown Current ($< 1\text{ mA}$)
- Reverse Bias Protected
- 2.9 V to 12 V Supply Range
- Thermal Shutdown Protection
- Current Limitation
- Requires Only 1.0 μF Output Capacitance for Stability
- Stable with Any Type of Capacitor (including MLCC)
- Available in 1.8 V, 2.5 V, 3.3 V, 5.0 V and Adjustable Output Voltages
- Power Good Output
- These are Pb-Free Devices

Applications

- PCMCIA Card
- Cellular Phones
- Camcorders and Cameras
- Networking Systems, DSL/Cable Modems
- Cable Set-Top Box
- MP3/CD Players
- DSP Supply
- Displays and Monitors



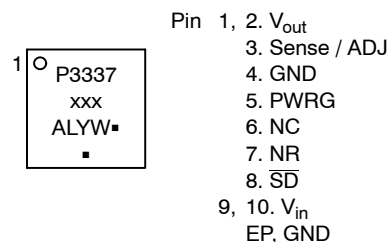
ON Semiconductor®

<http://onsemi.com>



DFN10
MN SUFFIX
CASE 485C

MARKING DIAGRAM



xxx = Specific Device Marking

A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 15 of this data sheet.

NCP3337

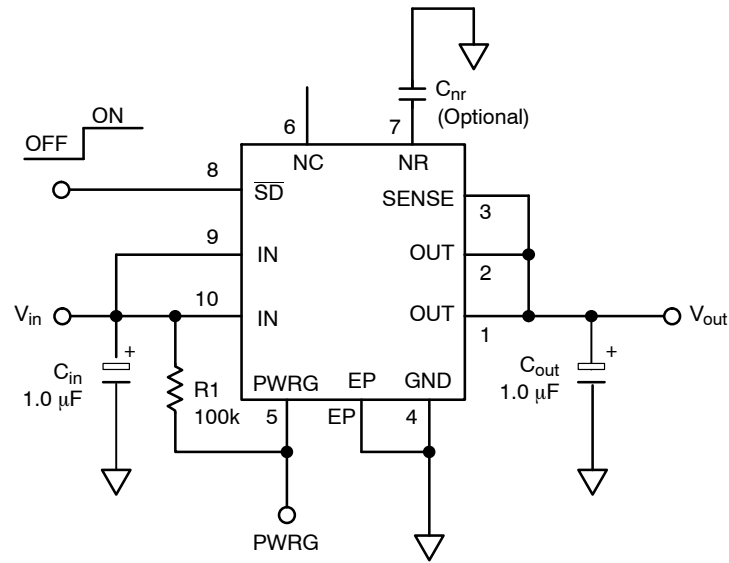


Figure 1. Typical Fixed Version Application Schematic

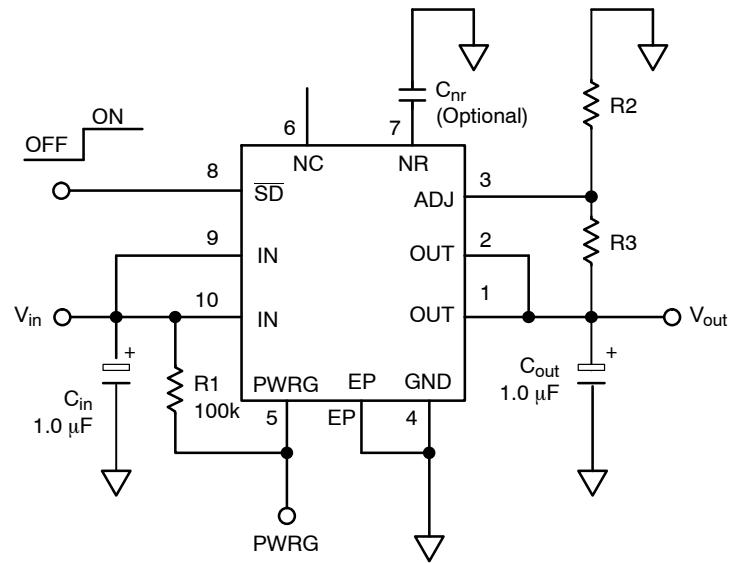


Figure 2. Typical Adjustable Version Application Schematic

NCP3337

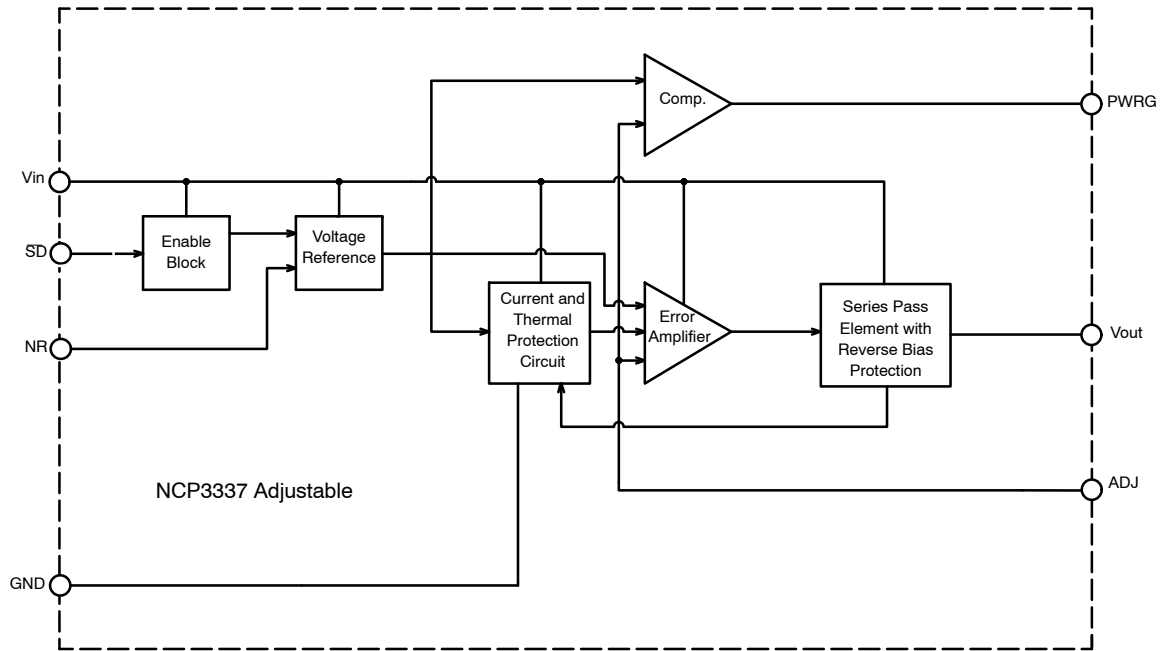


Figure 3. Block Diagram, Adjustable Output Version

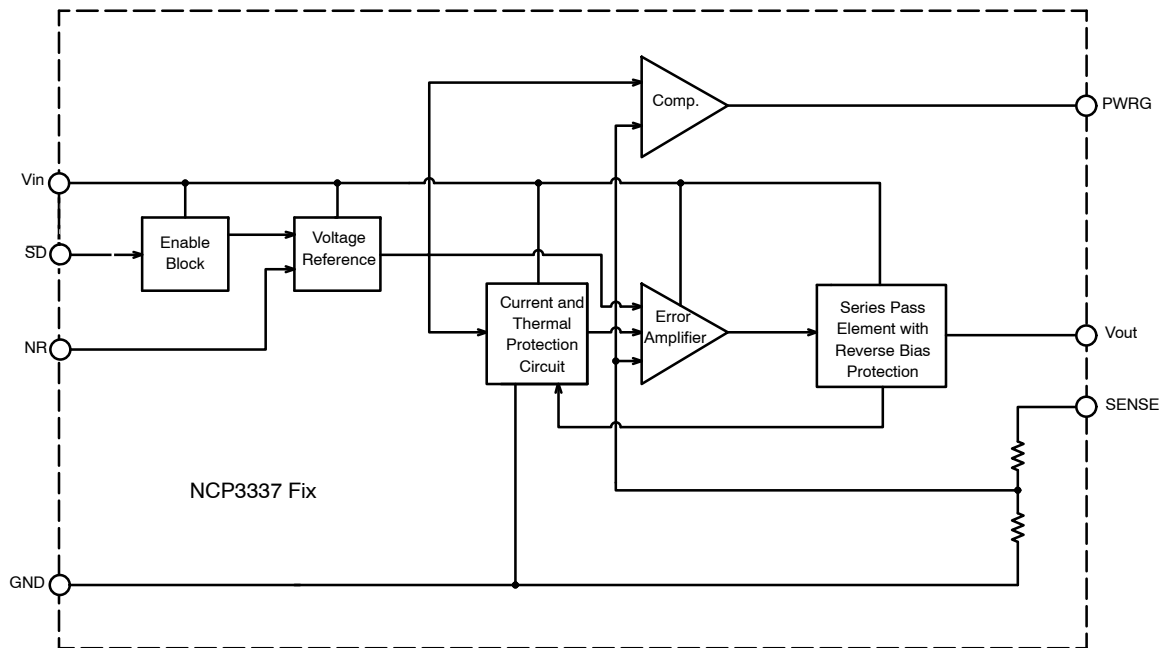


Figure 4. Block Diagram, Fixed Output Version

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1, 2	V _{out}	Regulated output voltage. Bypass to ground with C _{out} ≥ 1.0 μF
3	SENSE/ADJ	For output voltage sensing, connect to Pins 1 and 2. at Fixed output Voltage version Adjustable pin at Adjustable output version
4	GND	Power Supply Ground
5	PWRG	Power Good
6	NC	Not Connected
7	NR	Noise Reduction Pin. This is an optional pin used to further reduce noise.
8	SD	Shutdown pin. When not in use, this pin should be connected to the input pin.
9, 10	V _{in}	Power Supply Input Voltage
EPAD	EPAD	Exposed thermal pad should be connected to ground.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V _{in}	−0.3 to +16	V
Output Voltage	V _{out}	−0.3 to V _{in} +0.3 or 10 V*	V
PWRG Pin Voltage	V _{PWRG}	−0.3 to +16	V
Shutdown Pin Voltage	V _{sh}	−0.3 to +16	V
Junction Temperature Range	T _J	−40 to +150	°C
Storage Temperature Range	T _{stg}	−50 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NOTE: This device series contains ESD protection and exceeds the following tests:

Human Body Model (HBM) JESD 22-A114-B

Machine Model (MM) JESD 22-A115-A

*Which ever is less. Reverse bias protection feature valid only if (V_{out} − V_{in}) ≤ 7 V.

THERMAL CHARACTERISTICS

Characteristic	Test Conditions (Typical Value)		Unit
	Min Pad Board (Note 1)	1" Pad Board (Note 1)	
Junction-to-Air, θJA	215	66	°C/W
Junction-to-Pin, J-L4	58	18	°C/W

1. As mounted on a 35 x 35 x 1.5 mm FR4 Substrate, with a single layer of a specified copper area of 2 oz (0.07 mm thick) copper traces and heat spreading area. JEDEC 51 specifications for a low and high conductivity test board recommend a 2 oz copper thickness. Test conditions are under natural convection or zero air flow.

NCP3337

ELECTRICAL CHARACTERISTICS – 5 V ($V_{out} = 5.0$ V typical, $V_{in} = 5.4$ V, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, unless otherwise noted, Note 2)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage (Accuracy) $V_{in} = 5.4$ V to 7.3 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = 25^{\circ}\text{C}$	V_{out}	-0.90% 4.955	5	0.90% 5.045	V
Output Voltage (Accuracy) $V_{in} = 5.4$ V to 7.3 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	V_{out}	-1.40% 4.930	5	1.40% 5.070	V
Output Voltage (Accuracy) $V_{in} = 5.4$ V to 7.3 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	V_{out}	-1.50% 4.925	5	1.50% 5.075	V
Line Regulation $V_{in} = 5.4$ V to 12 V, $I_{load} = 0.1$ mA	$Line_{Reg}$		0.04		mV/V
Load Regulation $V_{in} = 5.4$ V, $I_{load} = 0.1$ mA to 500 mA	$Load_{Reg}$		0.04		mV/mA
Dropout Voltage (See Application Note) $I_{load} = 500$ mA $I_{load} = 300$ mA $I_{load} = 50$ mA $I_{load} = 0.1$ mA	V_{DO}			340 230 110 10	mV
Peak Output Current (See Figure 14)	I_{pk}	500	700	830	mA
Short Output Current (See Figure 14) $V_{in} < 7$ V, $T_A = 25^{\circ}\text{C}$	I_{sc}			930	mA
Thermal Shutdown / Hysteresis	T_J		160/10		$^{\circ}\text{C}$
Ground Current In Regulation $I_{load} = 500$ mA (Note 4) $I_{load} = 300$ mA (Note 4) $I_{load} = 50$ mA $I_{load} = 0.1$ mA In Dropout $V_{in} = 3.2$ V, $I_{load} = 0.1$ mA In Shutdown $V_{SD} = 0$ V	I_{GND} I_{GNDsh}		9 4.6 0.8 –	14 7.5 2.5 220 500 1	mA μA μA μA
Output Noise $C_{nr} = 0$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ μF $C_{nr} = 10$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ μF	V_{noise}		93 58		μVrms
Power Good Voltage Low Threshold Hysteresis High Threshold	V_{elft}	93	95 2 97	99	% of V_{out}
Power Good Pin Voltage Saturation ($I_{ef} = 1.0$ mA)	V_{efdo}		200		mV
Power Good Pin Leakage	I_{efleak}		1		μA
Power Good Blanking Time (Note 3)	t_{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V_{SD}	2		0.4	V
SD Input Current, $V_{SD} = 0$ V to 0.4 V or $V_{SD} = 2.0$ V to V_{in}	I_{SD}		0.07	1	μA
Output Current In Shutdown Mode, $V_{out} = 0$ V	I_{OSD}		0.07	1	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND ($V_{in} = 0$ V, $V_{out_forced} = 5$ V)	I_{OUTR}		10		μA

- Performance guaranteed over the operating temperature range by design and/or characterization, production tested at $T_J = T_A = 25^{\circ}\text{C}$. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
- Can be disabled per customer request.
- T_A must be greater than 0°C .

NCP3337

ELECTRICAL CHARACTERISTICS – 3.3 V ($V_{out} = 3.3\text{ V}$ typical, $V_{in} = 3.7\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, unless otherwise noted, Note 5)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage (Accuracy) $V_{in} = 3.7\text{ V}$ to 7.3 V , $I_{load} = 0.1\text{ mA}$ to 500 mA , $T_A = 25^\circ\text{C}$	V_{out}	-0.90% 3.270	3.3	0.90% 3.330	V
Output Voltage (Accuracy) $V_{in} = 3.7\text{ V}$ to 7.3 V , $I_{load} = 0.1\text{ mA}$ to 500 mA , $T_A = 0^\circ\text{C}$ to $+85^\circ\text{C}$	V_{out}	-1.40% 3.254	3.3	1.40% 3.346	V
Output Voltage (Accuracy) $V_{in} = 3.7\text{ V}$ to 7.3 V , $I_{load} = 0.1\text{ mA}$ to 500 mA , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	V_{out}	-1.50% 3.250	3.3	1.50% 3.350	V
Line Regulation $V_{in} = 3.7\text{ V}$ to 12 V , $I_{load} = 0.1\text{ mA}$	$Line_{Reg}$		0.04		mV/V
Load Regulation $V_{in} = 3.7\text{ V}$, $I_{load} = 0.1\text{ mA}$ to 500 mA	$Load_{Reg}$		0.04		mV/mA
Dropout Voltage (See Application Note) $I_{load} = 500\text{ mA}$ $I_{load} = 300\text{ mA}$ $I_{load} = 50\text{ mA}$ $I_{load} = 0.1\text{ mA}$	V_{DO}		340 230 110 10		mV
Peak Output Current (See Figure 14)	I_{pk}	500	700	800	mA
Short Output Current (See Figure 14) $V_{in} < 7\text{ V}$, $T_A = 25^\circ\text{C}$	I_{sc}			900	mA
Thermal Shutdown / Hysteresis	T_J		160/10		$^\circ\text{C}$
Ground Current In Regulation $I_{load} = 500\text{ mA}$ (Note 7) $I_{load} = 300\text{ mA}$ $I_{load} = 50\text{ mA}$ $I_{load} = 0.1\text{ mA}$ In Dropout $V_{in} = 3.7\text{ V}$, $I_{load} = 0.1\text{ mA}$ In Shutdown $V_{SD} = 0\text{ V}$	I_{GND} I_{GNDsh}		9 4.6 0.8 –	14 7.5 2.5 220 500 1	mA μA
Output Noise $C_{nr} = 0\text{ nF}$, $I_{load} = 500\text{ mA}$, $f = 10\text{ Hz}$ to 100 kHz , $C_{out} = 10\text{ }\mu\text{F}$ $C_{nr} = 10\text{ nF}$, $I_{load} = 500\text{ mA}$, $f = 10\text{ Hz}$ to 100 kHz , $C_{out} = 10\text{ }\mu\text{F}$	V_{noise}		69 46		μV_{rms}
Power Good Voltage Low Threshold Hysteresis High Threshold	V_{elft}	93	95 2 97	99	% of V_{out}
Power Good Pin Voltage Saturation ($I_{ef} = 1.0\text{ mA}$)	V_{efdo}		200		mV
Power Good Pin Leakage	I_{efleak}		1		μA
Power Good Blanking Time (Note 6)	t_{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V_{SD}	2		0.4	V
SD Input Current, $V_{SD} = 0\text{ V}$ to 0.4 V or $V_{SD} = 2.0\text{ V}$ to V_{in}	I_{SD}		0.07	1	μA
Output Current In Shutdown Mode, $V_{out} = 0\text{ V}$	I_{OSD}		0.07	1	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND ($V_{in} = 0\text{ V}$, $V_{out_forced} = 3.3\text{ V}$)	I_{OUTR}		10		μA

- Performance guaranteed over the operating temperature range by design and/or characterization, production tested at $T_J = T_A = 25^\circ\text{C}$. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
- Can be disabled per customer request.
- T_A must be greater than 0°C .

ELECTRICAL CHARACTERISTICS – 2.5 V ($V_{out} = 2.5$ V typical, $V_{in} = 2.9$ V, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, unless otherwise noted, Note 8)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage (Accuracy) $V_{in} = 2.9$ V to 6.5 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = 25^{\circ}\text{C}$	V_{out}	-0.9% 2.477	2.5	+0.9% 2.523	V
Output Voltage (Accuracy) $V_{in} = 2.9$ V to 6.5 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	V_{out}	-1.4% 2.465	2.5	+1.4% 2.535	V
Output Voltage (Accuracy) $V_{in} = 2.9$ V to 6.5 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	V_{out}	-1.5% 2.462	2.5	+1.5% 2.538	V
Minimum Input Voltage	V_{inmin}		2.9		V
Line Regulation $V_{in} = 2.9$ V to 12 V, $I_{load} = 0.1$ mA	LineReg		0.04		mV/V
Load Regulation $V_{in} = 2.9$ V, $I_{load} = 0.1$ mA to 500 mA	LoadReg		0.04		mV/mA
Dropout Voltage (See Figure 10) $I_{load} = 500$ mA (Note 9) $I_{load} = 300$ mA (Note 9) $I_{load} = 50$ mA $I_{load} = 0.1$ mA	V_{DO}		340 230 110 10		mV
Peak Output Current (See Figures 14 and 18)	I_{pk}	500	700	800	mA
Short Output Current (See Figure 14) $V_{in} < 7$ V, $T_A = 25^{\circ}\text{C}$	I_{sc}			900	mA
Thermal Shutdown / Hysteresis	T_J		160/10		$^{\circ}\text{C}$
Ground Current In Regulation $I_{load} = 500$ mA (Note 9) $I_{load} = 300$ mA (Note 9) $I_{load} = 50$ mA $I_{load} = 0.1$ mA In Dropout $V_{in} = 2.4$ V, $I_{load} = 0.1$ mA In Shutdown $V_{SD} = 0$ V	I_{GND} I_{GNDsh}		9.0 4.6 0.8 –	14 7.5 2.5 220 500 1.0	mA μA
Output Noise $C_{nr} = 0$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ μF $C_{nr} = 10$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ μF	V_{noise}		56 35		μVrms μVrms
Power Good Voltage Low Threshold Hysteresis High Threshold	V_{elft}	93	95 2 97	99	% of V_{out}
Power Good Pin Voltage Saturation ($I_{ef} = 1.0$ mA)	V_{efdo}		200		mV
Power Good Pin Leakage	I_{efleak}		1.0		μA
Power Good Blanking Time (Note 10)	t_{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V_{SD}	2.0		0.4	V V
S_D Input Current, $V_{SD} = 0$ V to 0.4 V or $V_{SD} = 2.0$ V to V_{in}	I_{SD}		0.07	1.0	μA
Output Current In Shutdown Mode, $V_{out} = 0$ V	I_{OSD}		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND ($V_{in} = 0$ V, $V_{out_forced} = 2.5$ V)	I_{OUTR}		10		μA

8. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at $T_J = T_A = 25^{\circ}\text{C}$. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

9. T_A must be greater than 0°C .

10. Can be disabled per customer request.

NCP3337

ELECTRICAL CHARACTERISTICS – 1.8 V ($V_{out} = 1.8$ V typical, $V_{in} = 2.9$ V, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, unless otherwise noted, Note 11)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage (Accuracy) $V_{in} = 2.9$ V to 5.8 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = 25^{\circ}\text{C}$	V_{out}	-0.9% 1.783	1.8	+0.9% 1.817	V
Output Voltage (Accuracy) $V_{in} = 2.9$ V to 5.8 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	V_{out}	-1.4% 1.774	1.8	+1.4% 1.826	V
Output Voltage (Accuracy) $V_{in} = 2.9$ V to 5.8 V, $I_{load} = 0.1$ mA to 500 mA, $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	V_{out}	-1.5% 1.773	1.8	+1.5% 1.827	V
Minimum Input Voltage	V_{inmin}		2.9		V
Line Regulation $V_{in} = 2.9$ V to 12 V, $I_{load} = 0.1$ mA	LineReg		0.04		mV/V
Load Regulation $V_{in} = 2.9$ V, $I_{load} = 0.1$ mA to 500 mA	LoadReg		0.04		mV/mA
Dropout Voltage (See Figure 9) $I_{load} = 500$ mA (Notes 12, 13) $I_{load} = 300$ mA (Notes 12, 13) $I_{load} = 50$ mA (Notes 12, 13)	V_{DO}		620 230 95		mV
Peak Output Current (See Figures 14 and 17)	I_{pk}	500	700	830	mA
Short Output Current (See Figure 14) $V_{in} < 7$ V, $T_A = 25^{\circ}\text{C}$	I_{sc}			900	mA
Thermal Shutdown / Hysteresis	T_J		160/10		$^{\circ}\text{C}$
Ground Current In Regulation $I_{load} = 500$ mA (Note 12) $I_{load} = 300$ mA (Note 12) $I_{load} = 50$ mA $I_{load} = 0.1$ mA In Dropout $V_{in} = 2.2$ V, $I_{load} = 0.1$ mA In Shutdown $V_{SD} = 0$ V	I_{GND} I_{GNDsh}		9.0 4.6 0.8 –	14 7.5 2.5 220 500 1.0	mA μA
Output Noise $C_{nr} = 0$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ μF $C_{nr} = 10$ nF, $I_{load} = 500$ mA, $f = 10$ Hz to 100 kHz, $C_{out} = 10$ μF	V_{noise}		52 33		μVrms μVrms
Power Good Voltage Low Threshold Hysteresis High Threshold	V_{elft}	93	95 2 97	99	% of V_{out}
Power Good Pin Voltage Saturation ($I_{ef} = 1.0$ mA)	V_{efdo}		200		mV
Power Good Pin Leakage	I_{efleak}		1.0		μA
Power Good Blanking Time (Note 10)	t_{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V_{SD}	2.0		0.4	V V
SD Input Current, $V_{SD} = 0$ V to 0.4 V or $V_{SD} = 2.0$ V to V_{in}	I_{SD}		0.07	1.0	μA
Output Current In Shutdown Mode, $V_{out} = 0$ V	I_{OSD}		0.07	1.0	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND ($V_{in} = 0$ V, $V_{out_forced} = 1.8$ V)	I_{OUTR}		10		μA

11. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at $T_J = T_A = 25^{\circ}\text{C}$. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

12. T_A must be greater than 0°C .

13. Maximum dropout voltage is limited by minimum input voltage $V_{in} = 2.9$ V recommended for guaranteed operation.

NCP3337

ELECTRICAL CHARACTERISTICS – ADJUSTABLE ($V_{out} = 1.25\text{ V}$ typical, $V_{in} = 2.9\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, unless otherwise noted, Note 14)

Characteristic	Symbol	Min	Typ	Max	Unit
Reference Voltage (Accuracy) $V_{in} = 2.9\text{ V}$ to $V_{out} + 4.0\text{ V}$, $I_{load} = 0.1\text{ mA}$ to 500 mA , $T_A = 25^\circ\text{C}$	V_{ref}	-0.90% 1.239	1.25	0.90% 1.261	V
Reference Voltage (Accuracy) $V_{in} = 2.9\text{ V}$ to $V_{out} + 4.0\text{ V}$, $I_{load} = 0.1\text{ mA}$ to 500 mA , $T_A = 0^\circ\text{C}$ to $+85^\circ\text{C}$	V_{ref}	-1.40% 1.233	1.25	1.40% 1.268	V
Reference Voltage (Accuracy) (Note 18) $V_{in} = 2.9\text{ V}$ to $V_{out} + 4.0\text{ V}$, $I_{load} = 0.1\text{ mA}$ to 500 mA , $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	V_{ref}	-1.50% 1.231	1.25	1.50% 1.269	V
Line Regulation $V_{in} = 2.9\text{ V}$ to 12 V , $I_{load} = 0.1\text{ mA}$	$Line_{Reg}$		0.04		mV/V
Load Regulation $V_{in} = 2.9\text{ V}$ to 12 V , $I_{load} = 0.1\text{ mA}$ to 500 mA	$Load_{Reg}$		0.04		mV/mA
Dropout Voltage (See Application Note) ($V_{out} = 2.5\text{ V} - 10\text{ V}$) $I_{load} = 500\text{ mA}$ (Note 16) $I_{load} = 300\text{ mA}$ $I_{load} = 50\text{ mA}$ $I_{load} = 0.1\text{ mA}$	V_{DO}		340 230 110 10		mV
Peak Output Current (See Figure 14)	I_{pk}	500	700	830	mA
Short Output Current (See Figure 14) $V_{in} < 7\text{ V}$, $T_A = 25^\circ\text{C}$ $V_{out} \leq 3.3\text{ V}$ $V_{out} > 3.3\text{ V}$	I_{sc}			900 930	mA
Thermal Shutdown / Hysteresis	T_J		160/ 10		$^\circ\text{C}$
Ground Current In Regulation $I_{load} = 500\text{ mA}$ (Note 16) $I_{load} = 300\text{ mA}$ (Note 16) $I_{load} = 50\text{ mA}$ $I_{load} = 0.1\text{ mA}$ In Dropout $V_{in} = V_{out} + 0.1\text{ V}$ or 2.9 V (whichever is higher), $I_{load} = 0.1\text{ mA}$ In Shutdown $V_{SD} = 0\text{ V}$	I_{GND} I_{GNDsh}		9 4.6 0.8	14 7.5 2.5 220 500 1	mA μA
Output Noise $C_{nr} = 0\text{ nF}$, $I_{load} = 500\text{ mA}$, $f = 10\text{ Hz}$ to 100 kHz , $C_{out} = 10\text{ }\mu\text{F}$ $C_{nr} = 10\text{ nF}$, $I_{load} = 500\text{ mA}$, $f = 10\text{ Hz}$ to 100 kHz , $C_{out} = 10\text{ }\mu\text{F}$	V_{noise}		69 46		μV_{rms}
Power Good Voltage Low Threshold Hysteresis High Threshold	V_{elft}	93	95 2 97	99	% of V_{out}
Power Good Pin Voltage Saturation ($I_{ef} = 1.0\text{ mA}$)	V_{efdo}		200		mV
Power Good Pin Leakage	I_{efleak}		1		μA
Power Good Pin Blanking Time (Note 15)	t_{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V_{SD}	2		0.4	V
SD Input Current, $V_{SD} = 0\text{ V}$ to 0.4 V or $V_{SD} = 2.0\text{ V}$ to V_{in} $V_{in} \leq 5.4\text{ V}$ $V_{in} > 5.4\text{ V}$	I_{SD}		0.07	1 5	μA
Output Current In Shutdown Mode, $V_{out} = 0\text{ V}$	I_{OSD}		0.07	1	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND ($V_{in} = 0\text{ V}$, $V_{out_forced} = V_{out}(\text{nom}) \leq 7\text{ V}$) (Note 17)	I_{OUTR}		1		μA

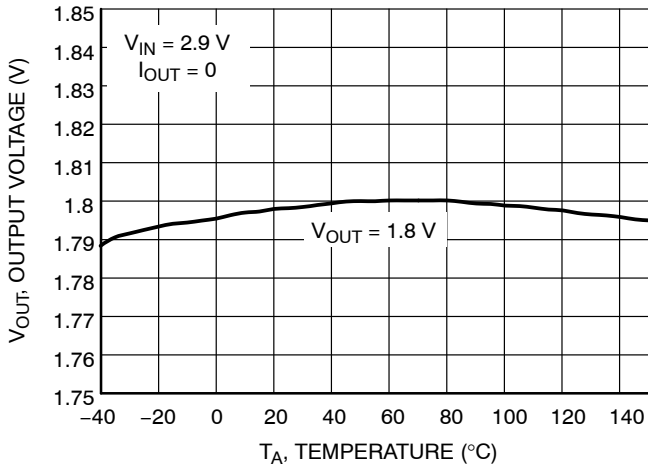
14. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at $T_J = T_A = 25^\circ\text{C}$. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

15. Can be disabled per customer request.

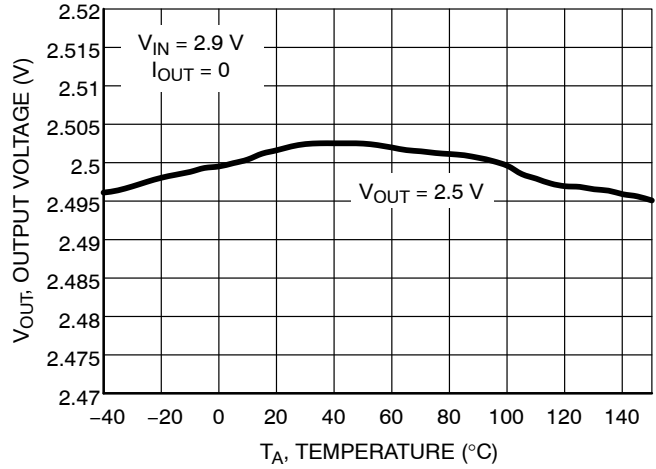
16. T_A must be greater than 0°C .

17. Reverse bias protection feature valid only if $V_{out} - V_{in} \leq 7\text{ V}$.

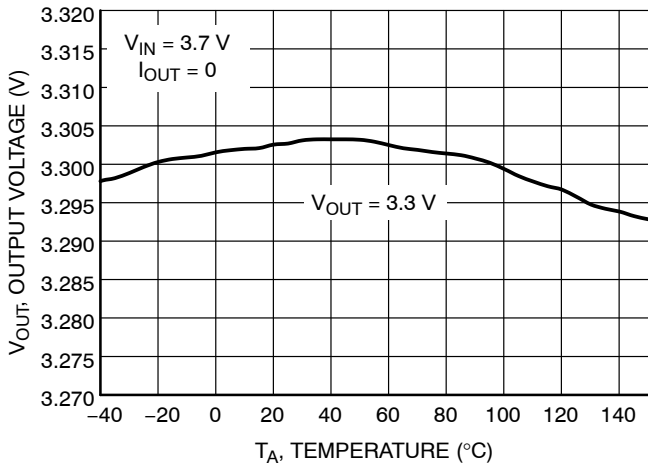
18. For output current capability for $T_A < 0^\circ\text{C}$, please refer to Figures 17 and 18.



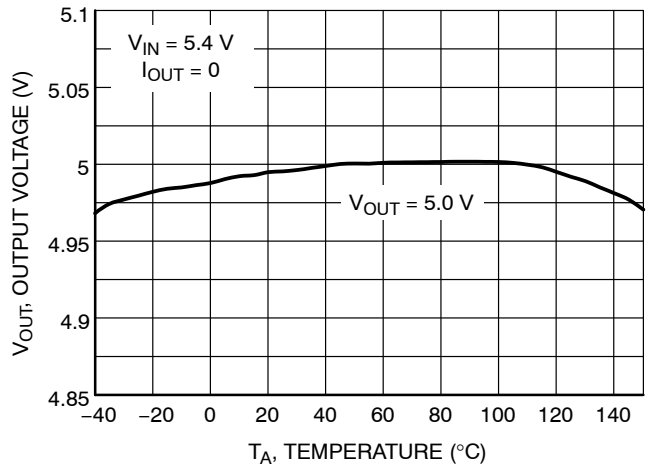
**Figure 5. Output Voltage vs. Temperature
1.8 V Version**



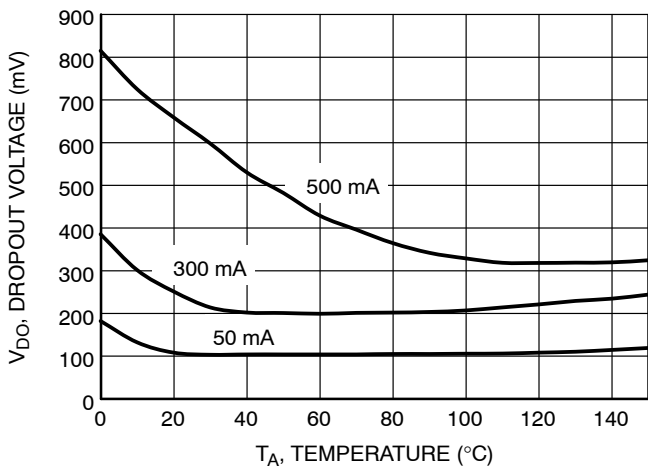
**Figure 6. Output Voltage vs. Temperature
2.5 V Version**



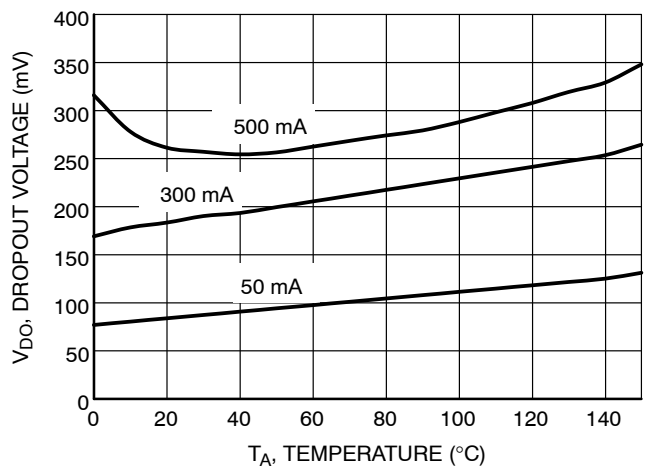
**Figure 7. Output Voltage vs. Temperature
3.3 V Version**



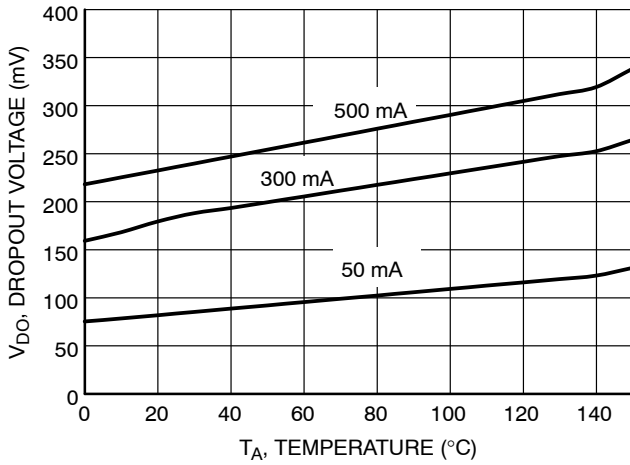
**Figure 8. Output Voltage vs. Temperature
5.0 V Version**



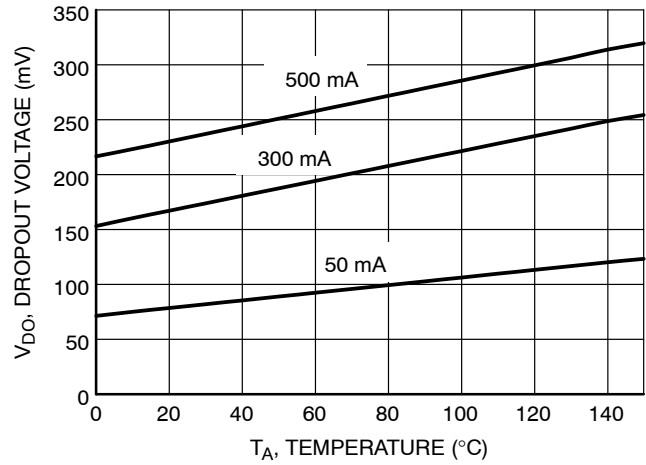
**Figure 9. Dropout Voltage vs. Temperature
1.8 V Version**



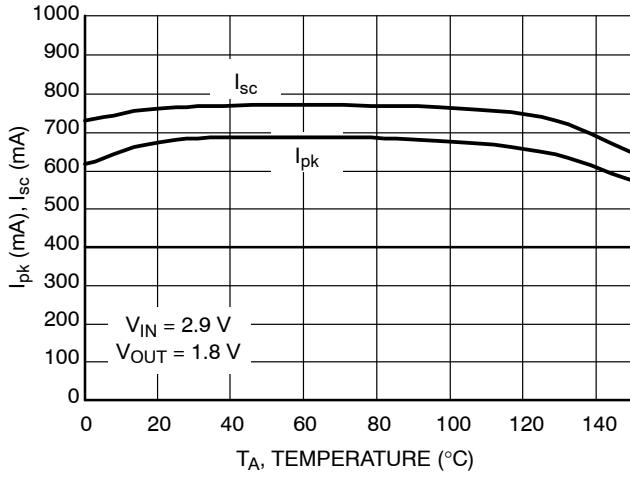
**Figure 10. Dropout Voltage vs. Temperature
2.5 V Version**



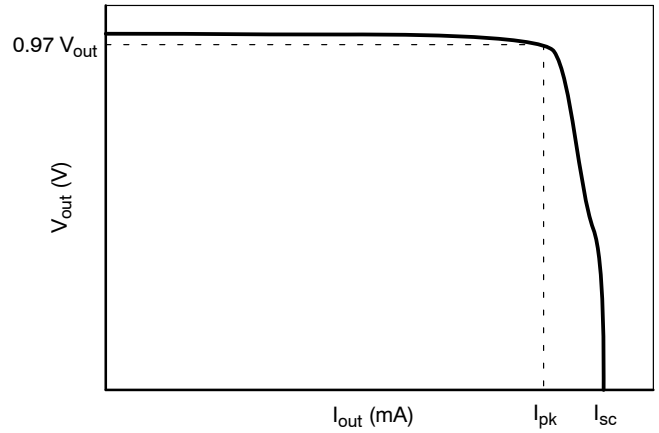
**Figure 11. Dropout Voltage vs. Temperature
3.3 V Version**



**Figure 12. Dropout Voltage vs. Temperature
5.0 V Version**



**Figure 13. Peak and Short Current
vs. Temperature**



(For specific values of I_{pk} and I_{sc} , please refer to Figure 13)

Figure 14. Output Voltage vs. Output Current

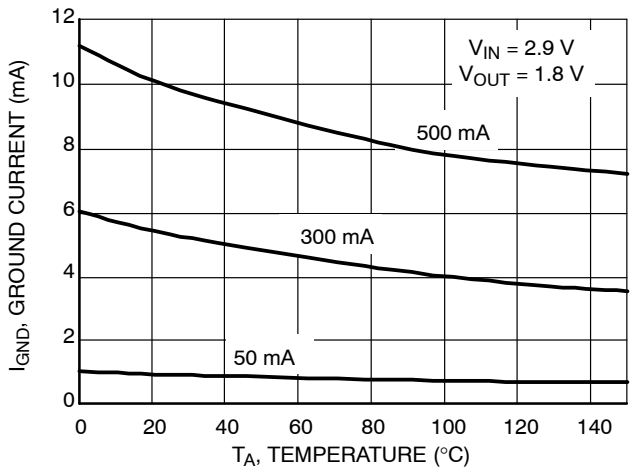


Figure 15. Ground Current vs. Temperature

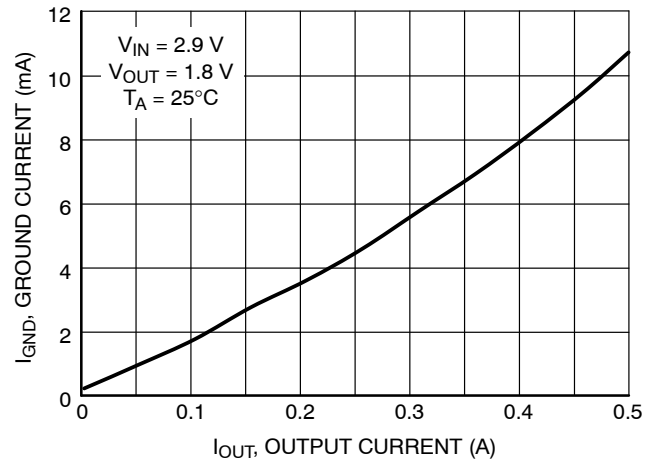


Figure 16. Ground Current vs. Output Current

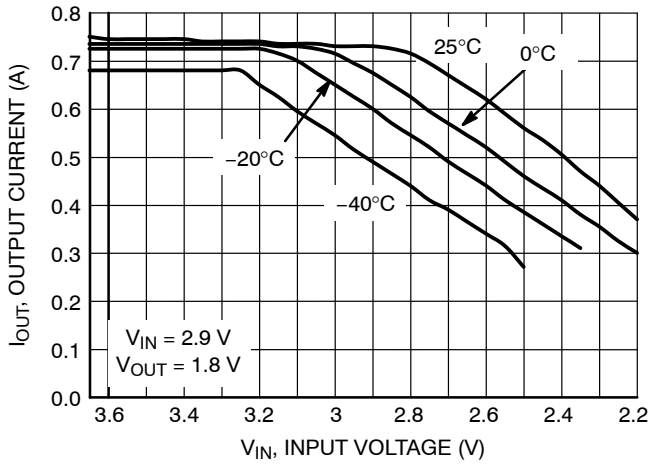


Figure 17. Output Current Capability for the 1.8 V Version

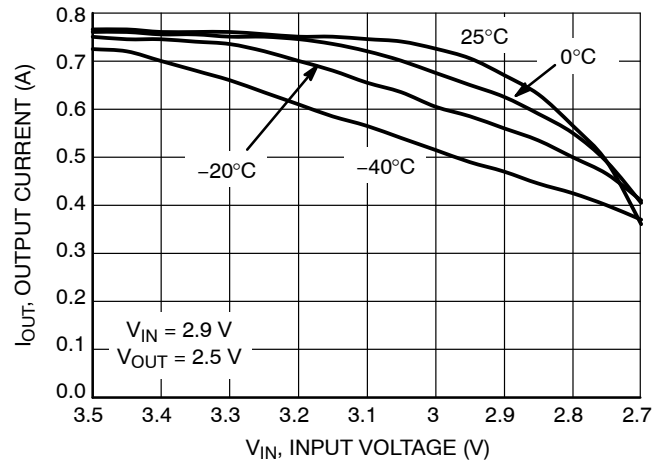


Figure 18. Output Current Capability for the 2.5 V Version

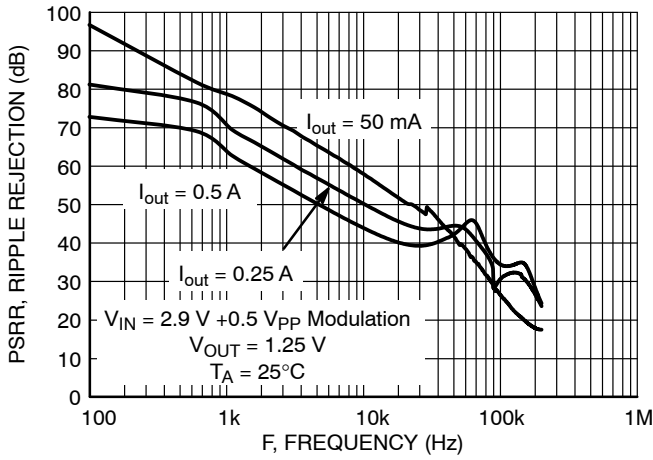


Figure 20. PSRR vs. Frequency Adjustable Version

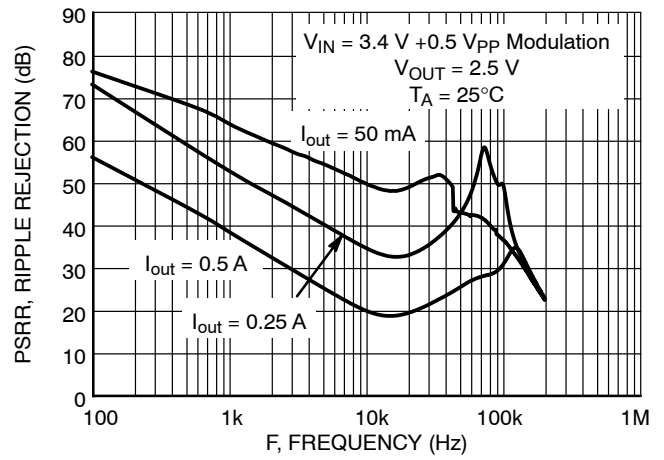


Figure 21. PSRR vs. Frequency 2.5 V Version

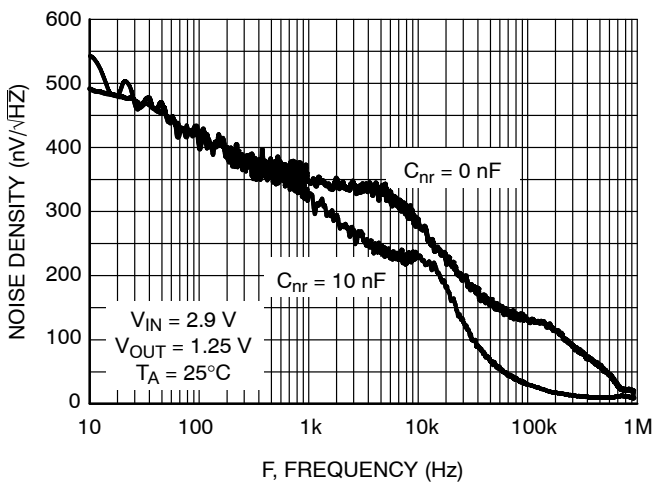


Figure 22. Output Noise Density Adjustable Version

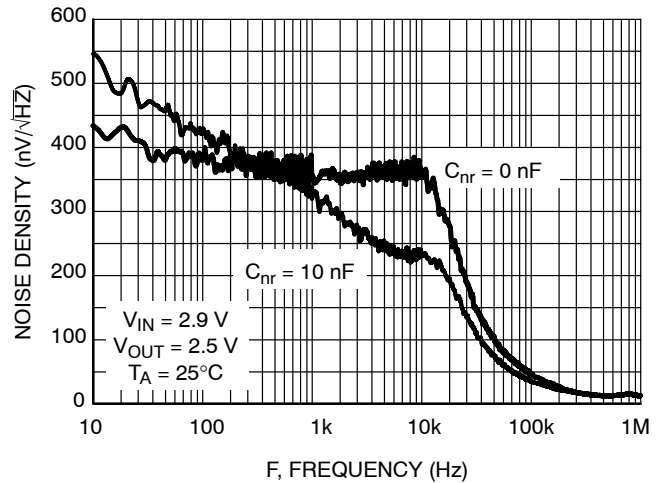


Figure 23. Output Noise Density 2.5 V Version

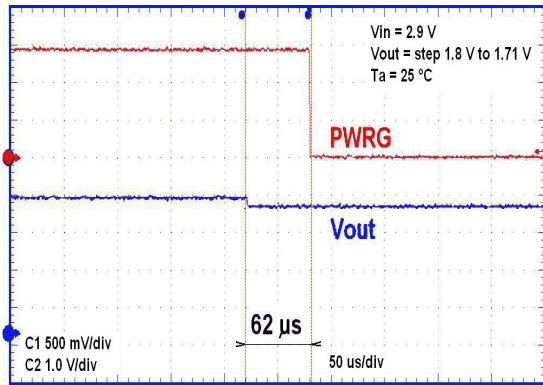


Figure 24. Power Good Activation

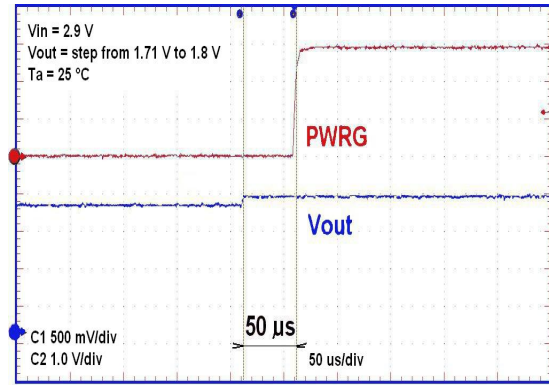


Figure 25. Power Good Inactivation

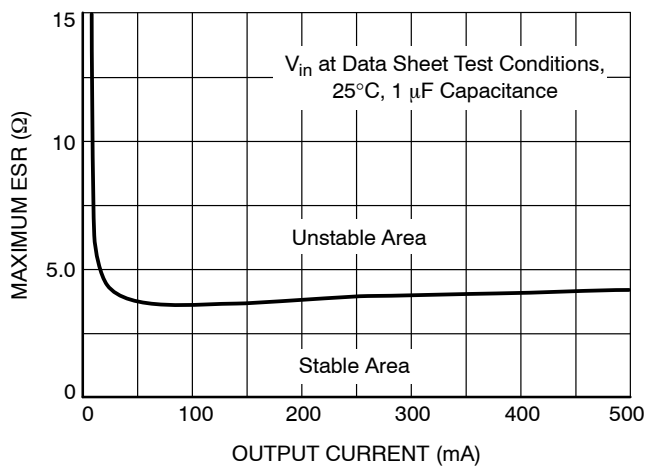


Figure 26. Stability with ESR vs. Output Current

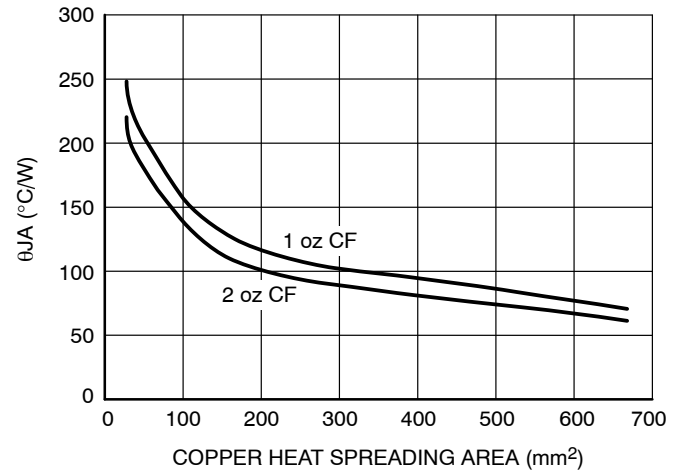


Figure 27. DFN10 Self-Heating Thermal Characteristics as a Function of Copper Area on the PCB

NOTE: Typical characteristics were measured with the same conditions as electrical characteristics.

APPLICATIONS INFORMATION

Reverse Bias Protection

Reverse bias is a condition caused when the input voltage goes to zero, but the output voltage is kept high either by a large output capacitor or another source in the application which feeds the output pin.

Normally in a bipolar LDO all the current will flow from the output pin to input pin through the PN junction with limited current capability and with the potential to destroy the IC.

Due to an improved architecture, the NCP3337 can withstand up to 7.0 V on the output pin with virtually no current flowing from output pin to input pin, and only negligible amount of current (tens of μA) flowing from the output pin to ground for infinite duration.

Input Capacitor

An input capacitor of at least 1.0 μF , any type, is recommended to improve the transient response of the regulator and/or if the regulator is located more than a few inches from the power source. It will also reduce the circuit's sensitivity to the input line impedance at high frequencies. The capacitor should be mounted with the shortest possible track length directly across the regular's input terminals.

Output Capacitor

The NCP3337 remains stable with any type of capacitor as long as it fulfills its 1.0 μF requirement. There are no constraints on the minimum ESR and it will remain stable up to an ESR of 5.0 Ω . Larger capacitor values will improve the noise rejection and load transient response.

Noise Reduction Pin

Output noise can be greatly reduced by connecting a 10 nF capacitor (C_{nr}) between the noise reduction pin and ground (see Figure 1). In applications where very low noise is not required, the noise reduction pin can be left unconnected.

Dropout Voltage

The voltage dropout is measured at 97% of the nominal output voltage.

Thermal Considerations

Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction

temperature is exceeded. This feature provides protection from a catastrophic device failure due to accidental overheating. This protection feature is not intended to be used as a substitute to heat sinking. The maximum power that can be dissipated, can be calculated with the equation below:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}} \quad (\text{eq. 1})$$

For improved thermal performance, contact the factory for the DFN package option. The DFN package includes an exposed metal pad that is specifically designed to reduce the junction to air thermal resistance, $R_{\theta JA}$.

Adjustable Operation

The output voltage can be set by using a resistor divider as shown in Figure 2 with a range of 1.25 to 10 V. The appropriate resistor divider can be found by solving the equation below. The recommended current through the resistor divider is from 10 μA to 100 μA . This can be accomplished by selecting resistors in the $\text{k}\Omega$ range. As result, the $I_{adj} * R_2$ becomes negligible in the equation and can be ignored.

$$V_{out} = 1.25 * (1 + R_3/R_2) + I_{adj} * R_2 \quad (\text{eq. 2})$$

Power Good Operation

The Power Good pin on the NCP3337 will produce a logic Low when it drops below the nominal output voltage. Refer to the electrical characteristics for the threshold values at which point the Power Good goes Low. When the NCP3337 is above the nominal output voltage, the Power Good will remain at logic High.

The external pullup resistor needs to be connected between V_{in} and the Power Good pin. A resistor of approximately 100 $\text{k}\Omega$ is recommended to minimize the current consumption. No pullup resistor is required if the Power Good output is not being used. The Power Good does not function during thermal shutdown and when the part is disabled.

NCP3337

ORDERING INFORMATION

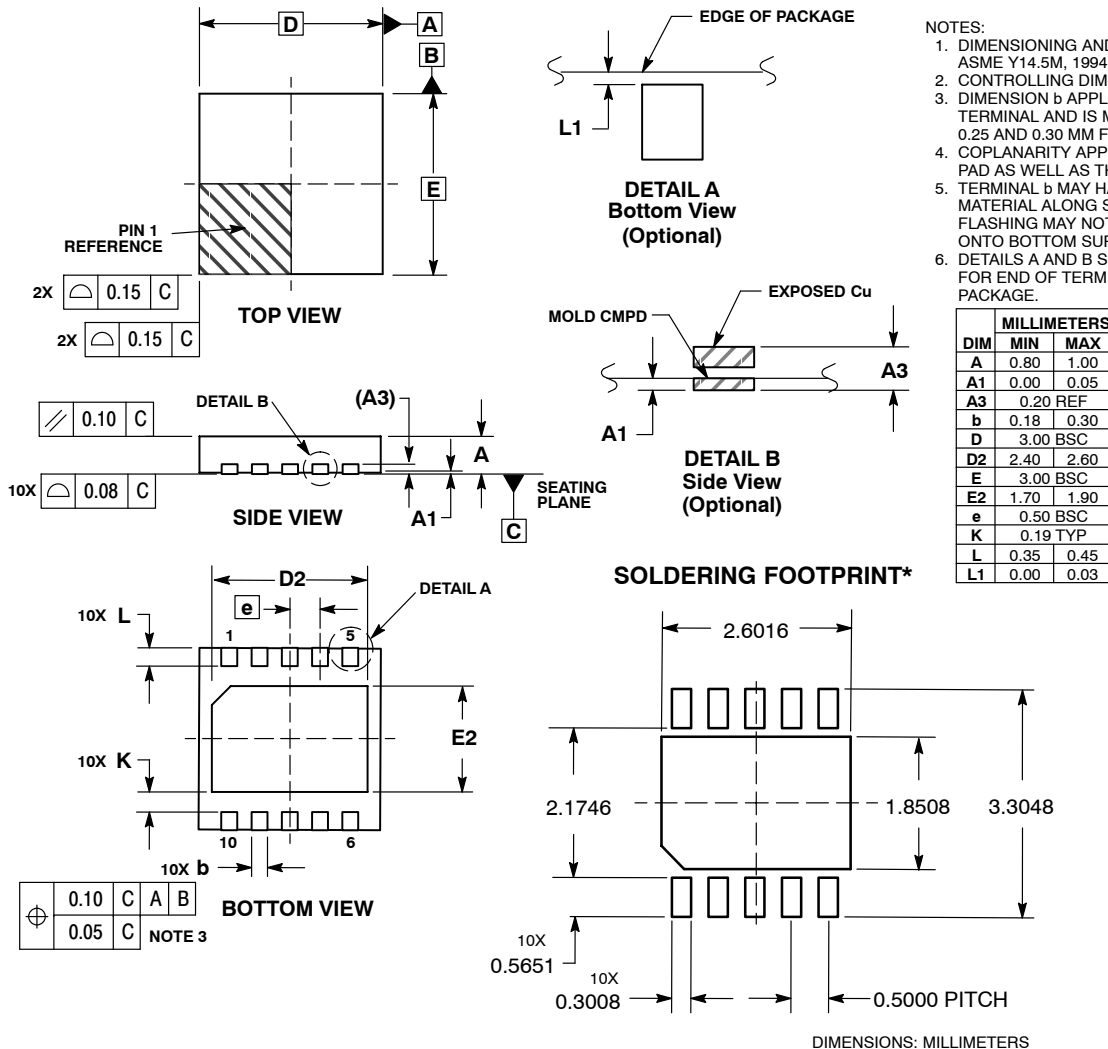
Device	Nominal Output Voltage	Marking	Package	Shipping†
NCP3337MN180R2G	1.8 V	P3337 180	DFN10 (Pb-Free)	3000 / Tape & Reel
NCP3337MN250R2G	2.5 V	P3337 250	DFN10 (Pb-Free)	3000 / Tape & Reel
NCP3337MN330R2G	3.3 V	P3337 330	DFN10 (Pb-Free)	3000 / Tape & Reel
NCP3337MN500R2G	5.0 V	P3337 500	DFN10 (Pb-Free)	3000 / Tape & Reel
NCP3337MNADJR2G	Adj	P3337 ADJ	DFN10 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*Please contact factory for other voltage options.

PACKAGE DIMENSIONS

DFN10, 3x3, 0.5P
CASE 485C-01
ISSUE B



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Micro8 is a trademark of International Rectifier.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9